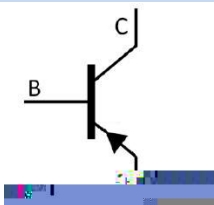
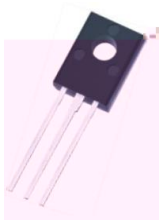


Rev.E Mar.-2016

TO-126F PNP Silicon PNP transistor in a TO-126F Plastic Package.

, , KTC2814
 Low collector saturation voltage, high speed switching time, complementary to, KTC2814.

Power amplifier application, power switching application.



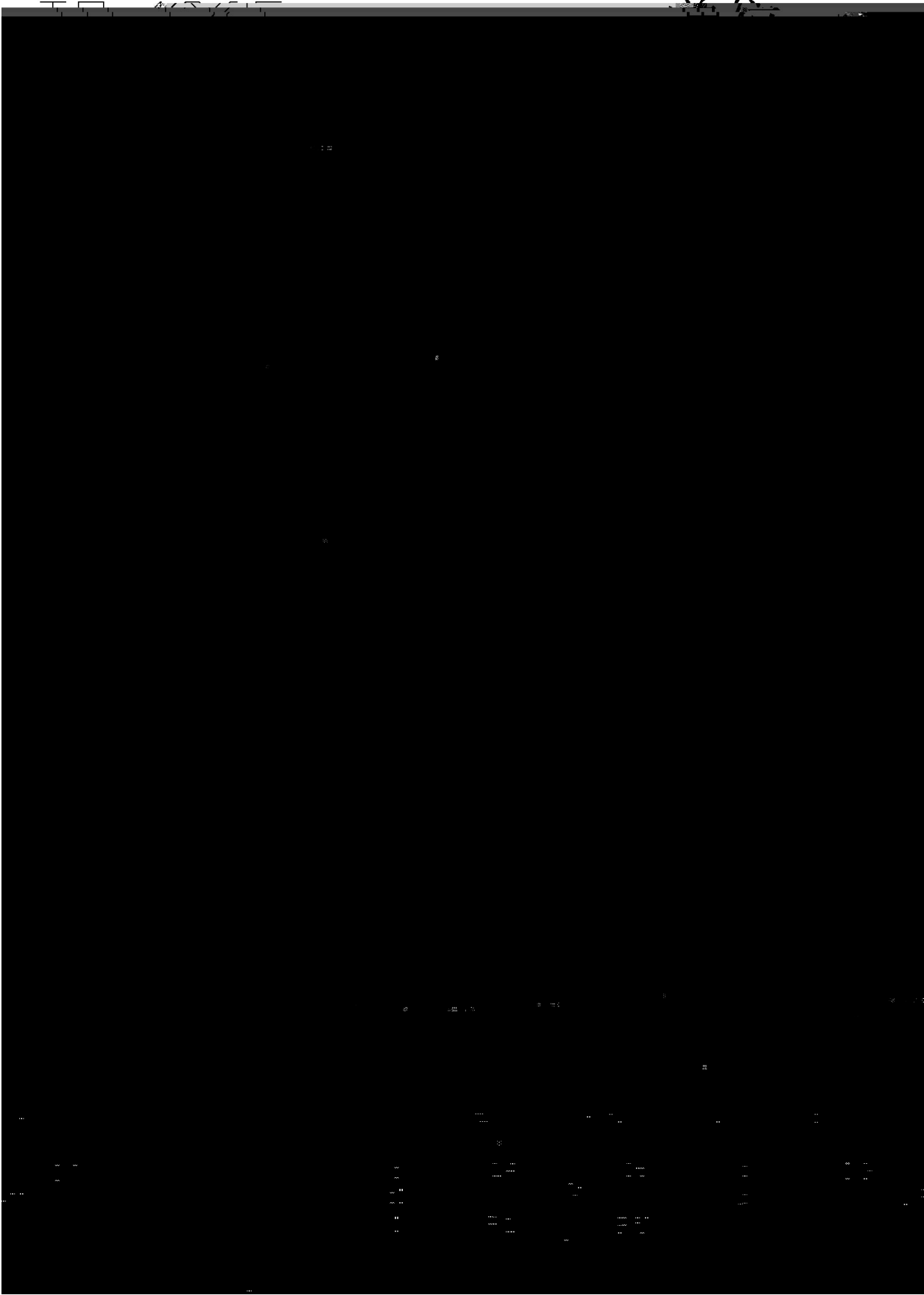
PIN1 Emitter PIN 2 Collector PIN 3 Base

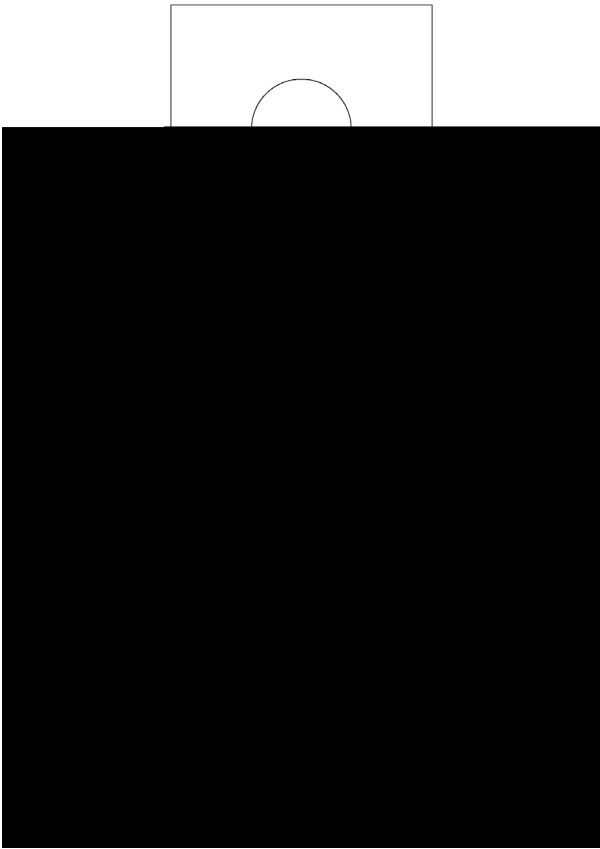
See Marking Instructions.

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-50	V
Collector to Emitter Voltage	V_{CEO}	-50	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous	I_C	-2.0	A
Collector Power Dissipation	P_C	1.5	W
Collector Power Dissipation	$P_C(T_C=25^\circ\text{C})$	10	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Emitter Breakdown Voltage	V_{CEO}	I_C				







BR

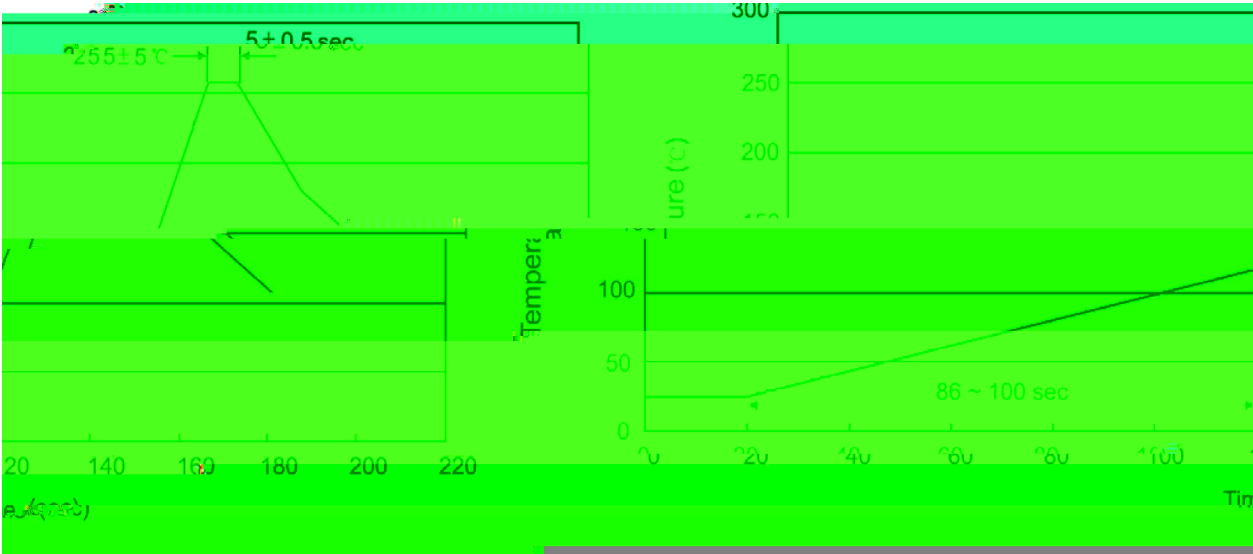
A1715

Note:

BR: Company Code

A1715: Product Type.

****: Lot No. Code, code change with Lot No.



- 1

25 150

60 90sec;
- 2

255±5

5±0.5sec;
- 3

2 10 /sec.
- Note:

1.Preheating:25~150 , Time:60~90sec.

2.Peak Temp.:255±5 , Duration:5±0.5sec.

3. Cooling Speed: 2~10 /sec.

270±5

10±1 sec.

Temp.:270±5

Time:10±1 sec

/ BULK

Package Type	Units	Dimension	(unit mm ³)
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